









CD54HC4051, CD74HC4051, CD54HCT4051, CD74HCT4051, CD54HC4052, CD74HC4052, CD54HCT4052, CD74HCT4052, CD54HC4053, CD74HC4053, CD54HCT4053, CD74HCT4053

SCHS122N - NOVEMBER 1997 - REVISED APRIL 2024

# CDx4HC405x, CD4HCT405x High-Speed CMOS Logic Analog **Multiplexer and Demultiplexer**

#### 1 Features

- Qualified for automotive applications
- Wide analog input voltage range: ±5V maximum
- Low ON-resistance:
  - 70 $\Omega$  typical (V<sub>CC</sub> V<sub>EE</sub> = 4.5V)
  - 40Ω typical (V<sub>CC</sub> V<sub>EE</sub> = 9V)
- Low crosstalk between switches
- Fast switching and propagation speeds
- Break-before-make switching
- Wide operating temperature range: -40°C to +125°C
- Operation control voltage: 4.5V to 5.5V
- Switch voltage: 0V to 10V
- Direct LSTTL input logic compatibility  $V_{IL} = 0.8V$  maximum,  $V_{IH} = 2V$  minimum
- CMOS input compatibility I<sub>I</sub> ≤ 1μA at V<sub>OI</sub> , V<sub>OH</sub>

### 2 Applications

- Digital radio
- Signal gating
- Factory automation
- **Televisions**
- **Appliances**
- Programmable logic circuits
- Sensors

### 3 Description

The CDx4HC405x and CDx4HCT405x device is a digitally controlled analog switch that uses silicon gate CMOS technology to achieve operating speeds similar to LSTTL with the low-power consumption of standard CMOS integrated circuits.

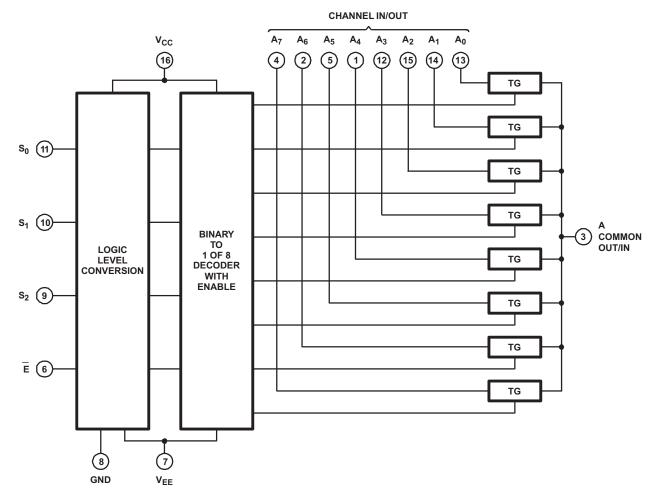
This analog multiplexer and demultiplexer controls analog voltages that may vary across the voltage supply range (for example,  $V_{CC}$  to  $V_{EE}$ ). It is a bidirectional switch that allows any analog input to be used as an output and vice versa. The switch has low ON resistance and low OFF leakages. In addition, this device has an enable control that, when high, disables all switches to their OFF state.

#### **Device Information**

PART NUMBER	T <sub>A</sub>	PACKAGE <sup>(1)</sup>	PACKAGE SIZE(2)	
CD54HCx405x		J (CDIP, 16)	19.56mm × 6.92mm	
CD74HCx405x		N (PDIP, 16)	19.30mm × 6.35mm	
	-55°C to 125°C	D (SOIC, 16)	9.9mm × 3.9mm	
		NS (SOP, 16)		10.3mm × 5.3mm
		PW (TSSOP, 16)	5mm × 4.4mm	

- For more information, see Section 11.
- The package size (length × width) is a nominal value and includes pins, where applicable.





**Functional Diagram of HCT4051** 



### **Table of Contents**

1 Features1	7.2 Functional Block Diagrams	. 24
2 Applications1	7.3 Feature Description	
3 Description1	7.4 Device Functional Modes	26
4 Pin Configuration and Functions4	8 Application and Implementation	. 27
5 Specifications7	8.1 Application Information	. 27
5.1 Absolute Maximum Ratings7	8.2 Typical Application	. 27
5.2 ESD Ratings7	8.3 Power Supply Recommendations	28
5.3 Thermal Information8	8.4 Layout	. 29
5.4 Recommended Operating Conditions8	9 Device and Documentation Support	30
5.5 Electrical Characteristics: HC Devices9	9.1 Documentation Support	. 30
5.6 Electrical Characteristics: HCT Devices	9.2 Receiving Notification of Documentation Updates	30
5.7 Switching Characteristics, VCC = 5V14	9.3 Support Resources	. 30
5.8 Switching Characteristics, CL = 50pF15	9.4 Trademarks	.30
5.9 Analog Channel Specifications18	9.5 Electrostatic Discharge Caution	30
5.10 Typical Characteristics20	9.6 Glossary	30
6 Parameter Measurement Information21	10 Revision History	. 30
7 Detailed Description24	11 Mechanical, Packaging, and Orderable	
7.1 Overview24	Information	. 31



## 4 Pin Configuration and Functions

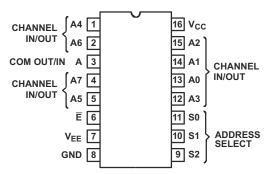


Figure 4-1. CDx4HCx4051 J, N, D, NS, PW Packages 16-Pin CDIP, PDIP, SOIC, SO, TSSOP (Top View)

Table 4-1. Pin Functions for CDxHCx4051B

PIN TYPE <sup>(1)</sup>		TVDE(1)	DESCRIPTION					
NAME	NO.	I I I PE\''	DESCRIPTION					
CH A4 IN/OUT	1	I/O	Channel 4 in/out					
CH A6 IN/OUT	2	I/O	Channel 6 in/out					
COM OUT/IN	3	I/O	Common out/in					
CH A7 IN/OUT	4	I/O	Channel 7 in/out					
CH A5 IN/OUT	5	I/O	Channel 5 in/out					
!E	6	1	Enable Channels (Active Low)					
V <sub>EE</sub>	7	_	Negative power input					
GND	8	_	Ground					
S2	9	I	Channel select 2					
S1	10	I	Channel select 1					
S0	11	I	Channel select 0					
CH A3 IN/OUT	12	I/O	Channel 3 in/out					
CH A0 IN/OUT	13	I/O	Channel 0 in/out					
CH A1 IN/OUT	14	I/O	Channel 1 in/out					
CH A2 IN/OUT	15	I/O	Channel 2 in/out					
V <sub>CC</sub>	16	_	Positive power input					

<sup>(1)</sup> I = input, O = output

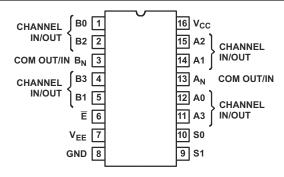


Figure 4-2. CDx4HCx4052 J, N, D, NS, PW Packages 16-Pin CDIP, PDIP, SOIC, SO, TSSOP (Top View)

#### Table 4-2. Pin Functions for CDx4HCx4052B

P	IN		DESCRIPTION
NAME	NO.	IYPE	DESCRIPTION
CH B0 IN/OUT	1	I/O	Channel B0 in/out
CH B2 IN/OUT	2	I/O	Channel B2 in/out
COM B OUT/IN	3	I/O	B common out/in
CH B3 IN/OUT	4	I/O	Channel B3 in/out
CH B1 IN/OUT	5	I/O	Channel B1 in/out
!E	6	1	Enable channels (Active Low)
V <sub>EE</sub>	7	_	Negative power input
GND	8	_	Ground
S1	9	ı	Channel select 1
S0	10	1	Channel select 0
CH A3 IN/OUT	11	I/O	Channel A3 in/out
CH A0 IN/OUT	12	I/O	Channel A0 in/out
COM A IN/OUT	13	I/O	A common out/in
CH A1 IN/OUT	14	I/O	Channel A1 in/out
CH A2 IN/OUT	15	I/O	Channel A2 in/out
V <sub>CC</sub>	16	_	Positive power input

<sup>(1)</sup> I = input, O = output



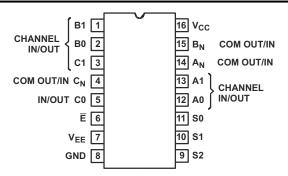


Figure 4-3. CDx4HCx4053 J, N, D, NS, PW Packages 16-Pin CDIP, PDIP, SOIC, SO, TSSOP (Top View)

Table 4-3. Pin Functions CDx4HCx4053B

PI	N	TYPE <sup>(1)</sup>	DESCRIPTION
NAME	NO.	IYPE	DESCRIPTION
B1IN/OUT	1	I/O	B channel Y in/out
B0 IN/OUT	2	I/O	B channel X in/out
C1 IN/OUT	3	I/O	C channel Y in/out
COM C OUT/IN	4	I/O	C common out/in
C0 IN/OUT	5	I/O	C channel X in/out
!E	6	I	Enable channels (Active Low)
V <sub>EE</sub>	7	_	Negative power input
GND	8	_	Ground
S2	9	ı	Channel select 2
S1	10	I	Channel select 1
S0	11	I	Channel select 0
A0 IN/OUT	12	I/O	A channel X in/out
A1 IN/OUT	13	I/O	A channel Y in/out
COM A OUT/IN	14	I/O	A common out/in
COM B OUT/IN	15	I/O	B common out/in
V <sub>CC</sub>	16	_	Positive power input

<sup>(1)</sup> I = input, O = output



### **5 Specifications**

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		·	MIN	MAX	UNIT
V <sub>CC</sub> – V <sub>EE</sub>			-0.5	10.5	V
V <sub>CC</sub>	DC Supply voltage		-0.5	7	V
V <sub>EE</sub>			0.5	-7	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < - 0.5V or V <sub>I</sub> > V <sub>CC</sub> + 0.5V	-20	20	mA
	DC switch diode current	$V_{I} < V_{EE} - 0.5V \text{ or } V_{I} > V_{CC} + 0.5V$	-20	20	mA
lok	DC switch current <sup>(2)</sup>	V <sub>I</sub> < V <sub>EE</sub> – 0.5V or V <sub>I</sub> > V <sub>CC</sub> + 0.5V	-25	25	mA
I <sub>CC</sub>	DC V <sub>CC</sub> or ground current		-50	50	mA
I <sub>EE</sub>	DC V <sub>EE</sub> current		-20		mA
V <sub>SEL</sub> or V <sub>EN</sub>	Logic control input pin voltage (	EN, Ax, SELx)	-0.5	30	V
T <sub>JMAX</sub>	Maximum junction temperature	Maximum junction temperature		150	°C
T <sub>LMAX</sub>	Maximum lead temperature	Maximum lead temperature Soldering 10 s		300	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 5.2 ESD Ratings

			VALUE	UNIT
	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins <sup>(1)</sup>	±500	V	
V <sub>(ESD)</sub>	Liectiostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±200	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

<sup>(2)</sup> All voltages are with respect to ground, unless otherwise specified.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



#### 5.3 Thermal Information

	THERMAL METRIC(1)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT
		16 PINS	16 PINS	16 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	77.3	99.3	116.5	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	56.2	59.6	51.9	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	52.6	65.7	73.9	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	33.7	21.5	4.7	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	52.1	65.1	73.2	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

### 5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	NOM MAX	UNIT
V	Supply voltage range (T <sub>A</sub> = full package temperature	CD54 and 74HC types	2	6	V
V <sub>CC</sub>	range) <sup>(2)</sup>	CD54 and 74HCT types	4.5	5.5	
V <sub>CC</sub> – V <sub>EE</sub>	Supply voltage range (T <sub>A</sub> = full package temperature range)	CD54 and 74HC types, CD54 and 74HCT types	2	10	V
V <sub>EE</sub>	Supply voltage range (T <sub>A</sub> = full package temperature range) <sup>(3)</sup>	CD54 and 74HC types, CD54 and 74HCT types	0	-6	V
VI	DC input control voltage		0	V <sub>CC</sub>	V
V <sub>IS</sub>	Analog switch I/O voltage		V <sub>EE</sub>	V <sub>CC</sub>	V
T <sub>A</sub>	Ambient temperature		-55	125	°C
		2V	0	1000	
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	4.5V	0	500	ns
		6V	0	400	

<sup>(1)</sup> For maximum reliability, nominal operating conditions must be selected so that operation is always within the ranges specified in the *Recommended Operating Conditions* table.

<sup>(2)</sup> All voltages referenced to GND unless otherwise specified.

<sup>(3)</sup> In certain applications, the external load resistor current may include both V<sub>CC</sub> and signal line components. To avoid drawing V<sub>CC</sub> current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.6V (calculated from r<sub>ON</sub> values shown in *Electrical Characteristics HC* and *Electrical Characteristics HCT* tables). No V<sub>CC</sub> current will flow through R<sub>L</sub> if the switch current flows into terminal 3 on the HC and HCT40511; terminals 3 and 13 on the HC and HCT4052; terminals 4, 14, and 15 on the HC and HCT4053.



## 5.5 Electrical Characteristics: HC Devices

Over operating free-air temperature range,  $V_{SUPPLY} = \pm 5V$ , and  $R_L = 100\Omega$ , (unless otherwise noted)

PARAMETER			ST CONDITION		inorwide rieted)		TYP I	MAX	UNIT
CD74HC405x									
	V <sub>IS</sub> (V)	V <sub>I</sub> (V)	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	TA				
					25°C	1.5			
				2	–40°C to +85°C	1.5			
					–55°C to +125°C	1.5			
					25°C	3.15			
Input High Voltage, V <sub>IH</sub> , Min				4.5	–40°C to +85°C	3.15			V
					–55°C to +125°C	3.15			
					25°C	4.2			
				6	–40°C to +85°C	4.2			
					–55°C to +125°C	4.2			
					25°C			0.5	
				2	–40°C to +85°C			0.5	
					–55°C to +125°C			0.5	
					25°C			1.35	
Input Low Voltage, V <sub>IL</sub> , Max				4.5	–40°C to +85°C			1.35	V
					–55°C to +125°C			1.35	
					25°C			1.8	
				6	–40°C to +85°C			1.8	
					–55°C to +125°C			1.8	



### 5.5 Electrical Characteristics: HC Devices (continued)

Over operating free-air temperature range,  $V_{SUPPLY} = \pm 5V$ , and  $R_L = 100\Omega$ , (unless otherwise noted)

PARAMETER				CONDITION			MIN TYP	MAX	UNIT	
						25°C	70	160		
				0	4.5	–40°C to +85°C		200		
						–55°C to +125°C		240		
						25°C	60	140		
		V <sub>CC</sub> or V <sub>EE</sub>		0	6	–40°C to +85°C		175	Ω	
						–55°C to +125°C		210		
						25°C	40	120		
			– V <sub>IL</sub> or V <sub>IH</sub>		-4.5	4.5	–40°C to +85°C		150	
r <sub>ON</sub>	4 - 2 4					–55°C to +125°C		180		
ON resistance	I <sub>O</sub> = 1mA -	IMA				25°C	90	180		
				0	4.5	–40°C to +85°C		225		
						–55°C to +125°C		270		
						25°C	80	160	1	
		V <sub>CC</sub> to V <sub>EE</sub>		0	6	–40°C to +85°C		200	Ω	
						–55°C to +125°C		240		
						25°C	45	130		
				-4.5	4.5	–40°C to +85°C		162		
						–55°C to +125°C		195		
Δr <sub>ON</sub>				0	4.5	25°C	10			
Maximum ON resistance				0	6	25°C	8.5		Ω	
between any two channels			-4.5	4.5	25°C	5				



## 5.5 Electrical Characteristics: HC Devices (continued)

Over operating free-air temperature range,  $V_{SUPPLY} = \pm 5V$ , and  $R_L = 100\Omega$ , (unless otherwise noted)

PARAMETER				CONDITIONS	•	orwice rioled)	MIN TYP	MAX	UNIT		
						25°C		±0.1			
	1 and 2			0	6	–55°C to 85°C		±1			
	channels			0		–55°C to 125°C		±1			
						25°C		±0.1			
	4053			-5	5	–55°C to 85°C		±1			
		For switch OFF: When				–55°C to 125°C		±1			
		$V_{IS} = V_{CC}$				25°C		±0.1			
	4	V <sub>OS</sub> = V <sub>EE</sub> ; When V <sub>IS</sub> =		0	6	–55°C to 85°C		±1			
I <sub>IZ</sub>	channels	$V_{EE}$ , $V_{OS}$ = $V_{CC}$ , For	V or V			–55°C to 125°C		±1			
Switch ON/OFF leakage current		switch ON:	V <sub>IL</sub> or V <sub>IH</sub>			25°C		±0.2	μA		
	4052	applicable		-5	5	–55°C to 85°C		±2	-		
	co	combination s of V <sub>IS</sub> and				–55°C to 125°C		±2			
		V <sub>OS</sub> voltage levels		0		25°C		±0.2			
	8 channels				6	–55°C to 85°C		±2			
						–55°C to 125°C		±2			
				-5		25°C		±0.4			
	4051				5	–55°C to 85°C		±4			
	4031					–55°C to 125°C		±4			
						25°C		±0.1			
I <sub>IL</sub>			V <sub>CC</sub> or	0	6	–55°C to 85°C		±1	μA		
Control input leakage current			GND			–55°C to 125°C		±1	, p		
						25°C		12			
		When $V_{IS} = V_{EE}$ , $V_{OS} = V_{IS}$		0	6	–55°C to 85°C		80	1		
Quiescent Device Current,	0	V <sub>CC</sub>	V <sub>CC</sub> or			–55°C to 125°C		160			
I <sub>CC</sub> Max	I <sub>O</sub> = 0		GND			25°C		32	μΑ		
		When $V_{IS} = V_{CC}$ , $V_{OS} = V_{CC}$		-5	5	–55°C to 85°C		160			
		V <sub>CC</sub> , V <sub>OS</sub> –						–55°C to 125°C		320	



### 5.6 Electrical Characteristics: HCT Devices

Over operating free-air temperature range,  $V_{SUPPLY} = \pm 5V$ , and  $R_L = 100\Omega$ , (unless otherwise noted)<sup>(1)</sup>

PARAMETER				CONDITION	<u> </u>	·····	MIN	TYP	MAX	UNIT
CD74HCT405x										
		V <sub>IS</sub> (V)	V <sub>I</sub> (V)	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	T <sub>A</sub>				
						25°C	2			
nput High Voltage, V <sub>IH</sub> , Min					4.5 to 5.5	–40°C to +85°C	2			V
						–55°C to +125°C	2			
						25°C			0.8	
Input Low Voltage, V <sub>IL</sub> , Max					4.5 to 5.5	–40°C to +85°C			0.8	V
						–55°C to +125°C			0.8	
						25°C		70	160	
				0	4.5	–40°C to +85°C			200	
		\\				–55°C to +125°C			240	
		V <sub>CC</sub> or V <sub>EE</sub>				25°C		40	120	
				-4.5	4.5	–40°C to +85°C			150	Ω
r <sub>on</sub>						–55°C to +125°C			180	
ON resistance	I <sub>O</sub> = 1mA		V <sub>IL</sub> or V <sub>IH</sub>			25°C		90	180	
				0	4.5	–40°C to +85°C			225	
		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				–55°C to +125°C			270	
		V <sub>CC</sub> to V <sub>EE</sub>				25°C		45	130	
				-4.5	4.5	-40°C to +85°C			162	Ω
					–55°C to +125°C			195		
Δr <sub>ON</sub>				0	4.5	25°C		10		
Maximum ON resistance between any two channels				-4.5	4.5	25°C		5		Ω



### 5.6 Electrical Characteristics: HCT Devices (continued)

Over operating free-air temperature range,  $V_{SUPPLY} = \pm 5V$ , and  $R_{I} = 100\Omega$ , (unless otherwise noted)<sup>(1)</sup>

PARAMETER			TEST	CONDITIONS	3		MIN TY	P MAX	UNIT
						25°C		±0.1	
	1 and 2			0	6	–55°C to 85°C		±1	
	channels					–55°C to 125°C		±1	
						25°C		±0.1	
	4053			-5	5	–55°C to 85°C		±1	
	4000	For switch OFF: When				–55°C to 125°C		±1	
		$V_{IS} = V_{CC}$				25°C		±0.1	
	4	$V_{OS} = V_{EE};$ When $V_{IS} =$		0	6	–55°C to 85°C		±1	
I <sub>IZ</sub>	channels	$V_{EE}$ , $V_{OS}$ = $V_{CC}$ , For	V 0r.V			–55°C to 125°C		±1	μA
Switch ON/OFF leakage current		switch ON:	V <sub>IL</sub> or V <sub>IH</sub>			25°C		±0.2	μΑ
	4052	applicable		-5	5	–55°C to 85°C		±2	
	4032	combination s of V <sub>IS</sub> and		-5	3	–55°C to 125°C		±2	
	8 channels	V <sub>OS</sub> voltage levels		0		25°C		±0.2	
					6	–55°C to 85°C		±2	-
						–55°C to 125°C		±2	
				-5		25°C		±0.4	
	4051				5	–55°C to 85°C		±4	
						–55°C to 125°C		±4	
						25°C		±0.1	
I <sub>IL</sub>			See <sup>(1)</sup>	0	5.5	–55°C to 85°C		±1	μA
Control input leakage current					0.0	–55°C to 125°C		±1	μΑ
						25°C		12	
		When $V_{IS} = V_{EE}$ , $V_{OS} =$		0	5.5	–55°C to 85°C		80	
Quiescent Device Current, I <sub>CC</sub>	0	V <sub>CC</sub>	V <sub>CC</sub> or		0.0	–55°C to 125°C		160	
Max	I <sub>O</sub> = 0		GND			25°C		32	μA
		When $V_{IS} = V_{CC}$ , $V_{OS} = V_{CC}$		-4.5	5.5	–55°C to 85°C		160	
		V <sub>EE</sub>		-4.5	0.0	–55°C to 125°C		320	
						25°C	10	00 360	
Δl <sub>CC</sub> Additional quiescent device current per input pin: 1		ΔΙCC	V <sub>CC</sub> - 2.1		4.5 to 5.5	–55°C to 85°C		450	цΔ
unit load <sup>(2)</sup>		<b>A</b> 100	v CC - 2.1			–55°C to 125°C		490	μΑ

<sup>(1)</sup> Any voltage between V<sub>CC</sub> and GND.

<sup>(2)</sup> For dual-supply systems, theoretical worse-case ( $V_1 = 2.4V$ ,  $V_{CC} = 5.5V$ ) specification is 1.8mA.



## 5.7 Switching Characteristics, VCC = 5V

 $V_{CC}$  = 5V,  $T_A$  = 25°C, input  $t_r$ , $t_f$  = 6 ns

	Parameter	Test Co	nditions	C <sub>L</sub> (pF)	MIN NOM	MAX	UNIT
			CDx4HC4051		4		
			CDx4HCT4051		4		
		Switch IN to	CDx4HC4052	15	4		
t <sub>PHL</sub> , t <sub>PLH</sub>		OUT	CDx4HCT4052	15	4		
			CDx4HC4053		4		
			CDx4HCT4053		4		
			CDx4HC4051		27		
			CDx4HCT4051		35		
	Supply voltage range (T <sub>A</sub> = full package	Switch turn-off	CDx4HC4052	15	33		ns
$t_{PHZ}, t_{PLZ}$	temperature range)	(S or E)	CDx4HCT4052		33		
			CDx4HC4053		30		
			CDx4HCT4053		35		
		Switch turn-on	CDx4HC4051		19		
			CDx4HCT4051		23		
			CDx4HC4052		27		
t <sub>PZH</sub> , t <sub>PZL</sub>		(S or E)	CDx4HCT4052	15	29		
			CDx4HC4053		18		
			CDx4HCT4053		28		
			CDx4HC4051		50		
			CDx4HCT4051		52		
C Davis	C <sub>PD</sub> Power dissipation capacitance <sup>(1)</sup>		CDx4HC4052		74		
C <sub>PD</sub> Power			CDx4HCT4052		76		pF
			CDx4HC4053		38		
			CDx4HCT4053	1	42		

<sup>(1)</sup>  $C_{PD}$  is used to determine the dynamic power consumption, per package.  $P_D = C_{PD} \, v_{CC} \, ^2 \, f_i + \Sigma \, (C_L + C_S) \, V_{CC} \, ^2 \, f_0$ ,  $f_O = 0$  output frequency,  $f_I = 0$  input frequency,  $C_L = 0$  output load capacitance,  $C_S = 0$  switch capacitance,  $V_{CC} = 0$  supply voltage



## 5.8 Switching Characteristics, CL = 50pF

 $C_L$  = 50pF, input  $t_r$ ,  $t_f$  = 6 ns

Parameter		V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Test Co	nditions	MIN NON	I MAX	UNIT
				T <sub>A</sub> = 25°C	HC		60	
		0	2	T <sub>A</sub> = -40°C to +85°C	нс		75	
				T <sub>A</sub> = -55°C to +125°C	нс		90	
				T <sub>A</sub> = 25°C	HC, HCT		12	
		0	4.5	T <sub>A</sub> = -40°C to +85°C	нс, нст		15	
t <sub>PHL</sub> , t <sub>PLH</sub>			-	T <sub>A</sub> = -55°C to +125°C	нс, нст		18	ns
Propagation delay, switch in to	out			T <sub>A</sub> = 25°C	HC		10	115
		0	6	T <sub>A</sub> = -40°C to +85°C	нс		13	
				T <sub>A</sub> = -55°C to +125°C	нс		15	
				T <sub>A</sub> = 25°C	HC, HCT		8	
			4.5	T <sub>A</sub> = -40°C to +85°C	нс, нст		10	
				T <sub>A</sub> = -55°C to +125°C	нс, нст		12	
		0	2	T <sub>A</sub> = 25°C	HC		250	
				$T_A = -40$ °C to $+85$ °C	НС		340	
				T <sub>A</sub> = -55°C to +125°C	нс		400	
				T <sub>A</sub> = 25°C	HC, HCT		50	
		0	4.5	T <sub>A</sub> = -40°C to +85°C	нс, нст		56	
t <sub>PHZ</sub> , t <sub>PLZ</sub> Maximum switch turn OFF	4051			T <sub>A</sub> = -55°C to +125°C	нс, нст		68	ns
delay from S or E to switch	4031			T <sub>A</sub> = 25°C	HC		44	115
output		0	6	T <sub>A</sub> = -40°C to +85°C	нс		50	
				T <sub>A</sub> = -55°C to +125°C	нс		57	1
				T <sub>A</sub> = 25°C	HC, HCT		44	
		-4.5	4.5	T <sub>A</sub> = -40°C to +85°C	нс, нст		50	
				T <sub>A</sub> = -55°C to +125°C	нс, нст		55	



## 5.8 Switching Characteristics, CL = 50pF (continued)

 $C_1 = 50pF$ , input  $t_r$ ,  $t_f = 6$  ns

Parameter		V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Test Co	nditions	MIN NOM MA	X UNI
				T <sub>A</sub> = 25°C	HC	25	50
		0	2	$T_A = -40$ °C to +85°C	нс	34	10
				T <sub>A</sub> = -55°C to +125°C	нс	40	00
				T <sub>A</sub> = 25°C	HC, HCT	į.	50
		0	4.5	$T_A = -40^{\circ}C$ to +85°C	HC, HCT	(	53
t <sub>PHZ</sub> , t <sub>PLZ</sub>				T <sub>A</sub> = -55°C to +125°C	НС, НСТ	-	75
Maximum switch turn OFF	4052			T <sub>A</sub> = 25°C	НС	4	l5 ns
delay from S or E to switch output	.002	0	6	T <sub>A</sub> = -40°C to +85°C	нс	ţ	54
				T <sub>A</sub> = -55°C to +125°C	НС	(	65
				T - 25°C	НС	4	15
				T <sub>A</sub> = 25°C	HCT	4	15
	-4.5	4.5	4.5	4.5	HC	4	18
		-4.5	4.5		HCT		50
				$T_A = -55$ °C to	НС		57
				+125°C	HCT		57
	0			T <sub>A</sub> = 25°C	НС	25	50
		0	2	T <sub>A</sub> = -40°C to +85°C	нс	34	10
				T <sub>A</sub> = -55°C to +125°C	нс	40	00
				T - 05°C	НС	4	15
				T <sub>A</sub> = 25°C	HCT		50
		0	4 5	$T_A = -40$ °C to	HC		53
		U	4.5	+85°C	HCT		53
+				$T_A = -55$ °C to	HC	(	33
<sub>PHZ</sub> , t <sub>PLZ</sub> Maximum switch turn OFF	4052			+125°C	HCT	(	66
lelay from S or E to switch	4053			T <sub>A</sub> = 25°C	HC	4	ns I5
output		0	6	T <sub>A</sub> = -40°C to +85°C	нс		50
				T <sub>A</sub> = -55°C to +125°C	нс	ţ	55
				T - 05°C	НС	4	15
				T <sub>A</sub> = 25°C	HCT	4	15
		4.5	4.5	$T_A = -40$ °C to	НС		50
		-4.5	4.5	+85°C	HCT		50
				$T_A = -55^{\circ}C$ to	НС		55
				+125°C	HCT	į.	55



## 5.8 Switching Characteristics, CL = 50pF (continued)

 $C_1 = 50pF$ , input  $t_r$ ,  $t_f = 6$  ns

Parameter		V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Test Co	nditions	MIN	NOM	MAX	TINU
				T <sub>A</sub> = 25°C	HC			325	
		0	2	T <sub>A</sub> = -40°C to +85°C	НС			405	
				T <sub>A</sub> = -55°C to +125°C	нс			490	
				T 05°0	HC			45	
				T <sub>A</sub> = 25°C	HCT			55	
			4.5	$T_A = -40$ °C to	HC			56	
		0	4.5	+85°C	HCT			69	
				$T_A = -55$ °C to	HC			68	
PZL, t <sub>PZH</sub> Maximum switch turn	4054			+125°C	HCT			83	
ON delay from S or E to switch putput	4051			T <sub>A</sub> = 25°C	HC		•	38	ns
•		0	6	T <sub>A</sub> = -40°C to +85°C	нс			48	
				T <sub>A</sub> = -55°C to +125°C	НС			57	
					НС			36	
	-4.5			T <sub>A</sub> = 25°C	HCT			48	
				T <sub>A</sub> = -40°C to +85°C	НС			40	
		-4.5	4.5		HCT			55	
				$T_A = -55^{\circ}C$ to	НС			48	
				+125°C	HCT			60	
		0	2	T <sub>A</sub> = 25°C	HC			325	
				T <sub>A</sub> = -40°C to +85°C	НС			405	
				T <sub>A</sub> = -55°C to +125°C	нс			490	
				T 05°0	HC			65	
				T <sub>A</sub> = 25°C	HCT			70	
			4.5	$T_A = -40$ °C to	НС			81	
		0	4.5	+85°C	HCT			68	
				$T_A = -55^{\circ}C$ to	НС			98	
t <sub>PZL</sub> , t <sub>PZH</sub> Maximum switch turn ON delay from S or E to switch	4052			+125°C	HCT			105	no
output	4052			T <sub>A</sub> = 25°C	НС			55	ns
од.ра.		0	6	$T_A = -40$ °C to +85°C	НС			69	
				T <sub>A</sub> = -55°C to +125°C	нс			83	
				T 0500	НС			46	
				T <sub>A</sub> = 25°C	HCT			48	
				$T_A = -40$ °C to	НС			58	
		-4.5	4.5	+85°C	HCT			60	
				T <sub>A</sub> = -55°C to	НС			69	
				+125°C	HCT			72	



## 5.8 Switching Characteristics, CL = 50pF (continued)

 $C_L = 50pF$ , input  $t_r$ ,  $t_f = 6$  ns

Parameter		V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Test Co	nditions	MIN NOM	MAX	UNIT
				T <sub>A</sub> = 25°C	НС		325	
		0	2	T <sub>A</sub> = -40°C to +85°C	нс		405	
				T <sub>A</sub> = -55°C to +125°C	нс		490	
				T <sub>A</sub> = 25°C	HC		44	
				1A - 23 C	HCT		48	
		0	4.5	$T_A = -40$ °C to	HC		55	
			4.5	+85°C	HCT		60	
				T <sub>A</sub> = -55°C to +125°C	HC		66	
t <sub>PZL</sub> , t <sub>PZH</sub> Maximum switch turn ON delay from S or E to switch	4053				HCT		72	ns
output	0		6	T <sub>A</sub> = 25°C	HC		37	
		0		T <sub>A</sub> = -40°C to +85°C	нс		47	
				T <sub>A</sub> = -55°C to +125°C	нс		56	
				T <sub>A</sub> = 25°C	HC		40	1
					HCT		48	
		-4.5	4.5	$T_A = -40^{\circ}C$ to	НС		45	
		-4.5	4.5	+85°C	HCT		55	
				$T_A = -55^{\circ}C$ to	HC		47	
				+125°C	HCT		60	
				T <sub>A</sub> = 25°C	HC, HCT		10	
C <sub>I</sub> Input (control) capacitance				T <sub>A</sub> = -40°C to +85°C	нс, нст		10	pF
				T <sub>A</sub> = -55°C to +125°C	нс, нст		10	

## **5.9 Analog Channel Specifications**

Typical values at T<sub>A</sub> = 25°C

Parameter	Test Conditions	HC, HCT TYPES	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	MIN NOM MAX	UNIT
C <sub>I</sub> Switch input capacitance		All			5	pF
•		4051			25	
C <sub>COM</sub> Common output capacitance		4052			12	pF
Common Carpat Capacitance		4053			8	
		4051	-2.25	2.25	145	- MHz
		4052	-2.25	2.25	165	
$f_{MAX}$	0 (1) (2)	4053	-2.25	2.25	200	
Minimum switch frequency response at -3 dB	See note <sup>(1)</sup> and <sup>(2)</sup>	4051	-4.5	4.5	180	
		4052	-4.5	4.5	185	
		4053	-4.5	4.5	200	
THD		All	-2.25	2.25	0.03 5	- %
Sine-wave distortion		All	-4.5	4.5	0.01 8	70

## **5.9 Analog Channel Specifications (continued)**

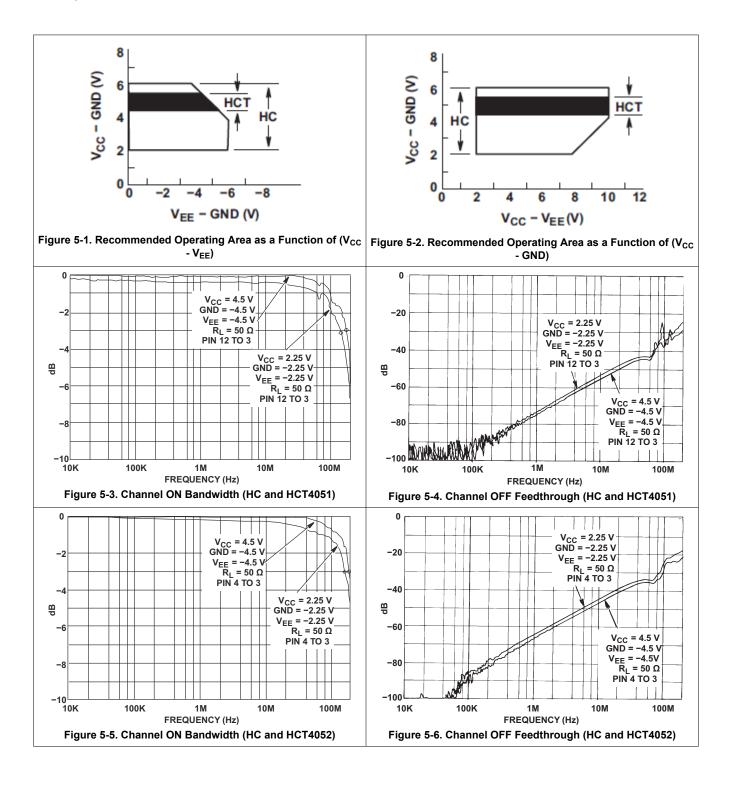
Typical values at T<sub>A</sub> = 25°C

Parameter	Test Conditions	HC, HCT TYPES	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	MIN NOM MAX	UNIT
		4051	-2.25	2.25	-73	
	See note <sup>(2)</sup> and <sup>(3)</sup>	4052	-2.25	2.25	-65	dB
Switch OFF signal foodthrough		4053	-2.25	2.25	-64	
Switch OFF signal feedthrough		4051	-4.5	4.5	-75	
		4052	-4.5	4.5	-67	
		4053	-4.5	4.5	-66	

- (1) Adjust input voltage to obtain 0 dBm at  $V_{OS}$  for  $f_{IN}$  = 1 MHz.
- (2) V<sub>is</sub> is centered at (V<sub>CC</sub> V<sub>EE</sub>) / 2.
- (3) Adjust input for 0 dBm.

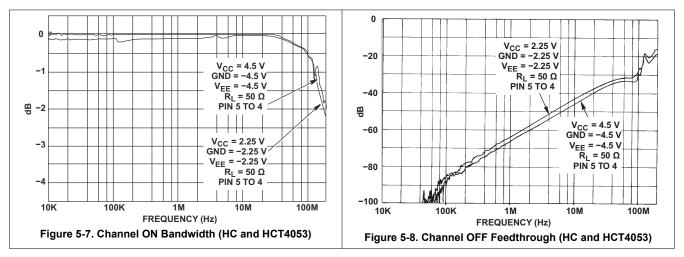


### **5.10 Typical Characteristics**

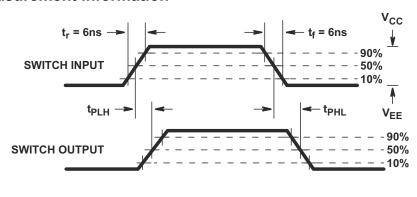




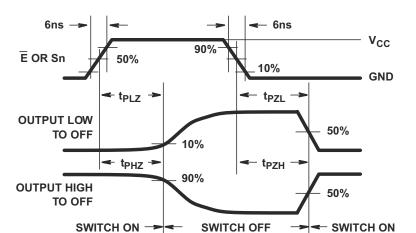
### **5.10 Typical Characteristics (continued)**

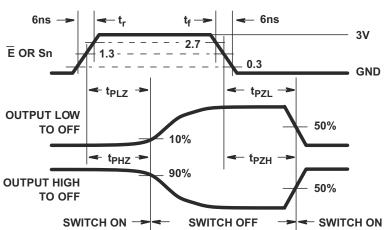


#### **6 Parameter Measurement Information**



(FIGURE A)





(FIGURE B) HC TYPES

(FIGURE C) HCT TYPES

Figure 6-1. Switch Propagation Delay, Turn-On, Turn-Off Times

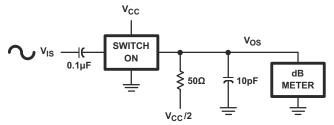
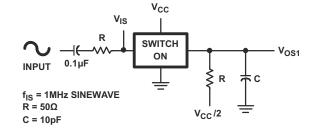


Figure 6-2. Frequency Response Test Circuit



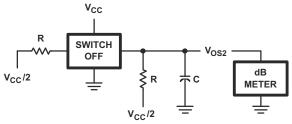


Figure 6-3. Crosstalk Between Two Switches Test Circuit

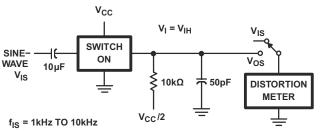


Figure 6-4. 1/4 Sine-Wave Distortion Test Circuit

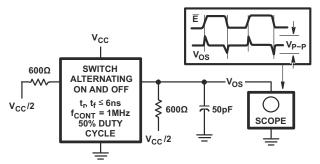


Figure 6-5. Control to Switch Feedthrough Noise Test Circuit

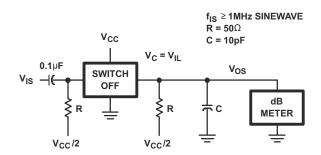


Figure 6-6. Switch OFF Signal Feedthrough

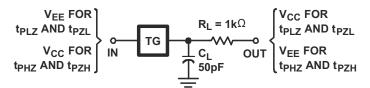


Figure 6-7. Switch ON/OFF Propagation Delay Test Circuit



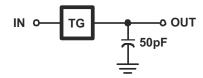


Figure 6-8. Switch In to Switch Out Propagation Delay Test Circuit



### 7 Detailed Description

#### 7.1 Overview

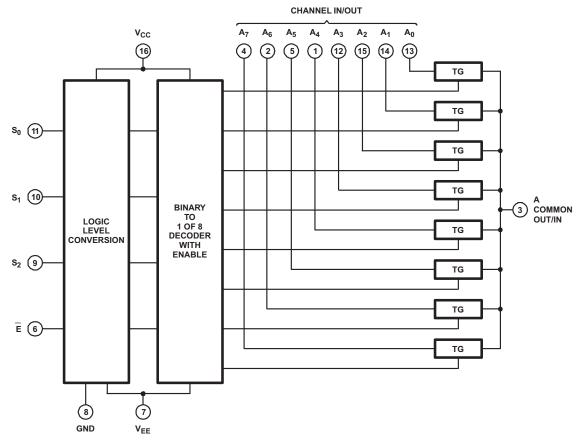
The CDx4HCx4051 devices are a single 8-channel multiplexer having three binary control inputs,  $S_0$ ,  $S_1$ , and  $S_2$  and an  $\overline{\text{ENABLE}}$  input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output.

The CDx4HCx4052 devices are a differential 4-channel multiplexer having two binary control inputs,  $S_0$  and  $S_1$ , and an  $\overline{\text{ENABLE}}$  input. The two binary input signals select 1 of 4 pairs of channels to be turned on and connect the analog inputs to the outputs.

The CDx4HCx4053 devices are a triple 2-channel multiplexer having three separate digital control inputs,  $S_0$ ,  $S_1$ , and  $S_2$  and an  $\overline{\text{ENABLE}}$  input. Each control input selects one of a pair of channels that are connected in a single-pole, double-throw configuration.

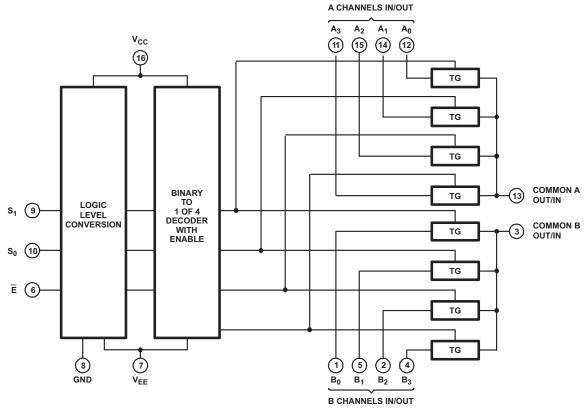
When these devices are used as demultiplexers, the CHANNEL IN/OUT terminals are the outputs and the COMMON OUT/IN terminals are the inputs.

#### 7.2 Functional Block Diagrams



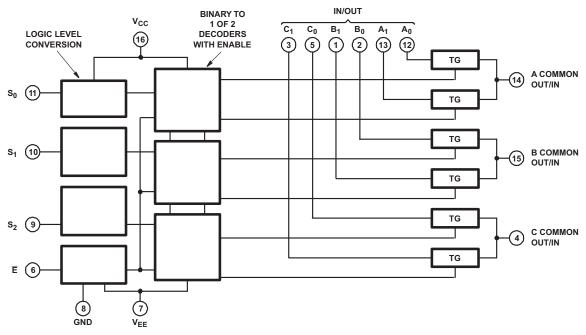
All inputs are protected by standard CMOS protection network.

Figure 7-1. CDx4HCx4051 Functional Block Diagram



All inputs are protected by standard CMOS protection network.

Figure 7-2. CDx4HCx4052 Functional Block Diagram



All inputs are protected by standard CMOS protection network.

Figure 7-3. CDx4HCx4053 Functional Block Diagram

### 7.3 Feature Description

The CDx4HCx405x line of multiplexers and demultiplexers can accept a wide range of analog signal levels from -5 to +5V. They have low ON resistance, typically  $70\Omega$  for  $V_{CC} - V_{EE} = 4.5$ V and  $40\Omega$  for  $V_{C} - V_{EE} = 4.5$ V, which allows for very little signal loss through the switch.

Binary address decoding on chip makes channel selection easy. When channels are changed, a break-before-make system eliminates channel overlap.

#### 7.4 Device Functional Modes

Table 7-1. CD54HC4051, CD74HC4051, CD54HCT4051, CD74HCT4051 Function Table (1)

	INPUT	STATES		ON
ENABLE	S <sub>2</sub>	S <sub>1</sub>	S <sub>0</sub>	CHANNEL
L	L	L	L	A0
L	L	L	Н	A1
L	L	Н	L	A2
L	L	Н	Н	A3
L	Н	L	L	A4
L	Н	L	Н	A5
L	Н	Н	L	A6
L	Н	Н	Н	A7
Н	X	Х	X	None

(1) X = Don't care

Table 7-2. CD54HC4052, CD74HC4052, CD54HCT4052, CD74HCT4052 Function Table (1)

	INPUT STATES					
ENABLE	S <sub>1</sub>	S <sub>0</sub>	CHANNELS			
L	L	L	A0, B0			
L	L	Н	A1, B1			
L	Н	L	A2, B2			
L	Н	Н	A3, B3			
Н	X	X	None			

(1) X = Don't care

Table 7-3. CD54HC4053, CD74HC4053, CD54HCT4053, CD74HCT4053 Function Table (1)

	INPUT	STATES		ON
ENABLE	S <sub>2</sub>	S <sub>1</sub>	S <sub>0</sub>	CHANNELS
L	L	L	L	C0, B0, A0
L	L	L	Н	C0, B0, A1
L	L	Н	L	C0, B1, A0
L	L	Н	Н	C0, B1, A1
L	Н	L	L	C1, B0, A0
L	Н	L	Н	C1, B0, A1
L	Н	Н	L	C1, B1, A0
L	Н	Н	Н	C1, B1, A1
Н	X	X	Х	None

(1) X = Don't care



### 8 Application and Implementation

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The CDx4HCx405x line of multiplexers and demultiplexers can be used for a wide variety of applications.

### 8.2 Typical Application

One application of the CD74HC4051 device is used in conjunction with a microcontroller to poll a keypad. Figure 8-1 shows the basic schematic for such a polling system. The microcontroller uses the channel-select pins to cycle through the different channels while reading the input to see if a user is pressing any of the keys. This is a very robust setup that allows for simultaneous key presses with very little power consumption. It also uses very few pins on the microcontroller. The down side of polling is that the microcontroller must frequently scan the keys for a press.

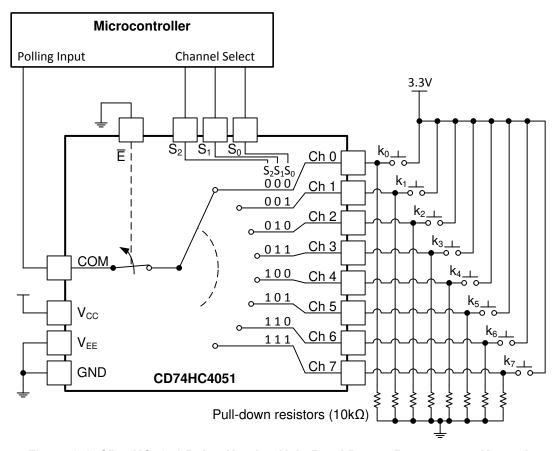


Figure 8-1. CD74HC4051 Being Used to Help Read Button Presses on a Keypad

#### 8.2.1 Design Requirements

These devices use CMOS technology and have balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions must be considered to prevent ringing.

See Table 8-1 for the input loading details.

**Table 8-1. HCT Input Loading Table** 

TYPE	INPUT	UNIT LOADS <sup>(1)</sup>		
4051, 4053	All	0.5		
4052	All	0.4		

(1) Unit load is ΔI<sub>CC</sub> limit specified in Section 5, for example, 360mA MAX at 25°C.

#### 8.2.2 Detailed Design Procedure

- 1. Recommended input conditions:
  - For switch time specifications, see propagation delay times in Section 5.5.
  - Inputs must not be pushed more than 0.5V above V<sub>DD</sub> or below V<sub>EE</sub>.
  - For input voltage level specifications for control inputs, see V<sub>IH</sub> and V<sub>IL</sub> in Section 5.5.
- 2. Recommended output conditions:
  - Outputs must not be pulled above V<sub>DD</sub> or below V<sub>EE</sub>.
- 3. Input and output current consideration:
  - The CDx4HCx405x series of parts do not have internal current-drive circuitry, and thus cannot sink or source current. Any current will be passed through the device.

#### 8.2.3 Application Curve

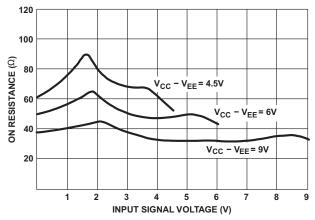


Figure 8-2. Typical ON Resistance vs Input Signal Voltage

#### 8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Section 5.5.

Each  $V_{CC}$  terminal must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a  $0.1\mu F$  bypass capacitor is recommended. If there are multiple pins labeled  $V_{CC}$ , then a  $0.01\mu F$  or  $0.022\mu F$  capacitor is recommended for each  $V_{CC}$  because the  $V_{CC}$  pins will be tied together internally. For devices with dual-supply pins operating at different voltages, for example  $V_{CC}$  and  $V_{DD}$ , a  $0.1\mu F$  bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A  $0.1\mu F$  and a  $1\mu F$  capacitor are commonly used in parallel. For best results, the bypass capacitor or capacitors must be installed as close as possible to the power terminal.



#### 8.4 Layout

#### 8.4.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change in width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This change in width upsets the transmission line characteristics, especially the distributed capacitance and self-inductance of the trace, thus resulting in the reflection. Not all PCB traces can be straight, so they will have to turn corners. Figure 8-3 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

#### 8.4.2 Layout Example

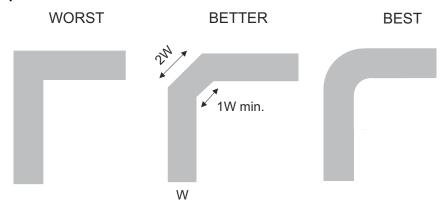


Figure 8-3. Trace Example

### 9 Device and Documentation Support

### 9.1 Documentation Support

#### 9.1.1 Related Documentation

For related documentation, see the following:

· Texas Instruments, Implications of Slow or Floating CMOS Inputs

### 9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 9.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 9.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

#### 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision M (May 2019) to Revision N (April 2024)	Page
Changed thermal metrics	8
Changed HC ICC at 25°C single/dual supply	
Changed HCT ICC at 25°C single/dual supply	
Changed: tPHZ/tPLZ typicals Switch turn-off (S or E)	
· Changed tPHZ/tPLZ maximum switch turn OFF delay from S or E to switch outp	ut for 4051/4052/4053 15
· Changed tPZL/tPZH maximum switch turn ON delay from S or E to switch outpu	t for 4051/405315
Changes from Revision L (February 2017) to Revision M (May 2019)	Page
Changes from Revision L (February 2017) to Revision M (May 2019)  • Changed Feature From: 7Ω Typical To: 70Ω Typical	<b>Page</b> 1
Changed Feature From: 7Ω Typical To: 70Ω Typical	1
<ul> <li>Changed Feature From: 7Ω Typical To: 70Ω Typical</li> <li>Changes from Revision K (September 2015) to Revision L (February 2017)</li> </ul>	Page
Changed Feature From: 7Ω Typical To: 70Ω Typical	Page7

SCHS122N - NOVEMBER 1997 - REVISED APRIL 2024

Page



O.	naliges from Revision 3 (February 2011) to Revision R (September 2013)
•	Added Military Disclaimer to Features list
	Removed Ordering Information table
	Add Device left medically Big Forestelly FOR Referential The medical state of the Reference of the Add Device and Device

### 11 Mechanical, Packaging, and Orderable Information

Changes from Povision I (February 2011) to Povision K (Sentember 2015)

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com

31-Oct-2024

## **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
5962-8775401EA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8775401EA CD54HC4053F3A	Sample
5962-8855601EA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8855601EA CD54HC4052F3A	Sample
5962-9065401MEA	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9065401ME A CD54HCT4051F3A	Sample
CD54HC4051F	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC4051F	Sample
CD54HC4051F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC4051F3A	Sample
CD54HC4052F	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC4052F	Sample
CD54HC4052F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8855601EA CD54HC4052F3A	Sampl
CD54HC4053F	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC4053F	Sampl
CD54HC4053F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8775401EA CD54HC4053F3A	Sampl
CD54HCT4051F3A	ACTIVE	CDIP	J	16	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9065401ME A CD54HCT4051F3A	Sampl
CD74HC4051E	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4051E	Samp
CD74HC4051EE4	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4051E	Samp
CD74HC4051M	OBSOLETI	E SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4051M	
CD74HC4051M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4051M	Samp
CD74HC4051M96G3	OBSOLETI	E SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4051M	
CD74HC4051M96G4	OBSOLETI	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4051M	
CD74HC4051MT	OBSOLETI	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4051M	
CD74HC4051NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4051M	Samp





31-Oct-2024 www.ti.com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HC4051NSRE4	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4051M	Samples
CD74HC4051PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4051	Samples
CD74HC4051PWRG4	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4051	
CD74HC4051PWT	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4051	
CD74HC4052E	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4052E	
CD74HC4052M	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4052M	
CD74HC4052M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4052M	Samples
CD74HC4052M96G4	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4052M	
CD74HC4052MT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4052M	
CD74HC4052NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4052M	Samples
CD74HC4052PW	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4052	
CD74HC4052PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-55 to 125	HJ4052	Samples
CD74HC4052PWRG4	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4052	
CD74HC4052PWT	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4052	
CD74HC4053E	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4053E	
CD74HC4053M	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4053M	
CD74HC4053M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-55 to 125	HC4053M	Samples
CD74HC4053M96G3	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4053M	
CD74HC4053M96G4	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4053M	
CD74HC4053MT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HC4053M	
CD74HC4053NSR	NRND	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4053M	
CD74HC4053PW	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4053	
CD74HC4053PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4053	Samples
CD74HC4053PWRG4	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4053	
CD74HC4053PWT	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HJ4053	
CD74HCT4051E	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4051E	
CD74HCT4051M	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT4051M	



www.ti.com 31-Oct-2024

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT4051M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4051M	Samples
CD74HCT4051M96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4051M	Samples
CD74HCT4051M96G4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4051M	Samples
CD74HCT4051MT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT4051M	
CD74HCT4052E	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4052E	
CD74HCT4052EE4	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4052E	
CD74HCT4052M	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT4052M	
CD74HCT4052M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4052M	Samples
CD74HCT4052M96G4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4052M	Samples
CD74HCT4052MT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT4052M	
CD74HCT4053E	NRND	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4053E	
CD74HCT4053M	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT4053M	
CD74HCT4053M96	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4053M	Samples
CD74HCT4053M96E4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4053M	Samples
CD74HCT4053M96G4	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4053M	Samples
CD74HCT4053MT	OBSOLETE	SOIC	D	16		TBD	Call TI	Call TI	-55 to 125	HCT4053M	
CD74HCT4053PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HK4053	Samples
CD74HCT4053PWT	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI	-55 to 125	HK4053	

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



www.ti.com 31-Oct-2024

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF CD54HC4051, CD54HC4052, CD54HC4053, CD54HC4051, CD74HC4051, CD74HC4052, CD74HC4053, CD74HC4051:

- Catalog: CD74HC4051, CD74HC4052, CD74HC4053, CD74HCT4051
- Automotive: CD74HC4051-Q1, CD74HCT4051-Q1, CD74HC4051-Q1. CD74HCT4051-Q1
- Enhanced Product: CD74HC4051-EP, CD74HC4051-EP
- Military: CD54HC4051, CD54HC4052, CD54HC4053, CD54HCT4051

#### NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

## **PACKAGE OPTION ADDENDUM**

www.ti.com 31-Oct-2024

• Military - QML certified for Military and Defense Applications



www.ti.com 28-Oct-2024

## TAPE AND REEL INFORMATION



# TAPE DIMENSIONS KO P1 BO W Cavity AO

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4051M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4051M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4051NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4051NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4051PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4051PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4052M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4052M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4052NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4052NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4052PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4052PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4053M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4053M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4053NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4053PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



# **PACKAGE MATERIALS INFORMATION**

www.ti.com 28-Oct-2024

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4053PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT4051M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4051M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4052M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4052M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4053M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4053M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4053PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT4053PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 28-Oct-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4051M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HC4051M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HC4051NSR	SO	NS	16	2000	353.0	353.0	32.0
CD74HC4051NSR	so	NS	16	2000	367.0	367.0	38.0
CD74HC4051PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
CD74HC4051PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HC4052M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HC4052M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HC4052NSR	so	NS	16	2000	353.0	353.0	32.0
CD74HC4052NSR	so	NS	16	2000	356.0	356.0	35.0
CD74HC4052PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
CD74HC4052PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HC4053M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HC4053M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HC4053NSR	SO	NS	16	2000	356.0	356.0	35.0
CD74HC4053PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HC4053PWR	TSSOP	PW	16	2000	353.0	353.0	32.0
CD74HCT4051M96	SOIC	D	16	2500	353.0	353.0	32.0



# **PACKAGE MATERIALS INFORMATION**

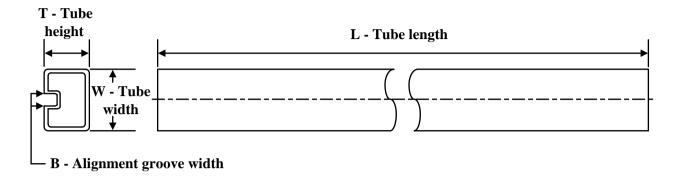
www.ti.com 28-Oct-2024

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HCT4051M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HCT4052M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HCT4052M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HCT4053M96	SOIC	D	16	2500	340.5	336.1	32.0
CD74HCT4053M96	SOIC	D	16	2500	353.0	353.0	32.0
CD74HCT4053PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
CD74HCT4053PWR	TSSOP	PW	16	2000	353.0	353.0	32.0



www.ti.com 28-Oct-2024

## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC4051E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4051EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4052E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4052E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4053E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4053E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4051E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4051E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4052E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4052E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4052EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4052EE4	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4053E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HCT4053E	N	PDIP	16	25	506	13.97	11230	4.32

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



## NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



# D (R-PDS0-G16)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated